

3 GHz HF-Synthesizer HM8135

HAMEG®
Instruments
A Rohde & Schwarz Company



Key facts

- Frequency range: 1 Hz to 3 GHz
- High dynamic output power: -135 dBm to +13 dBm
- Frequency resolution: 1 Hz
- High spectral purity, excellent SWEEP mode
- Modulation modes: AM, FM, pulse, phase, FSK, PSK
- Internal modulation (10 Hz to 200 kHz): sine, square, triangle, ramp
- External Ref.-Input/Output (10 MHz) via BNC-connector
- HM8135: TCXO (temperature stability: $\pm 0.5 \times 10^{-6}$)
HM8135-X: OCXO (temperature stability: $\pm 1.0 \times 10^{-8}$)
- R RS-232/USB dual interface, IEEE-488 (GPIB) optional

Technical Data

3 GHz HF-Synthesizer HM8135

All data valid at 23°C after 30 minutes warm-up..

Frequency

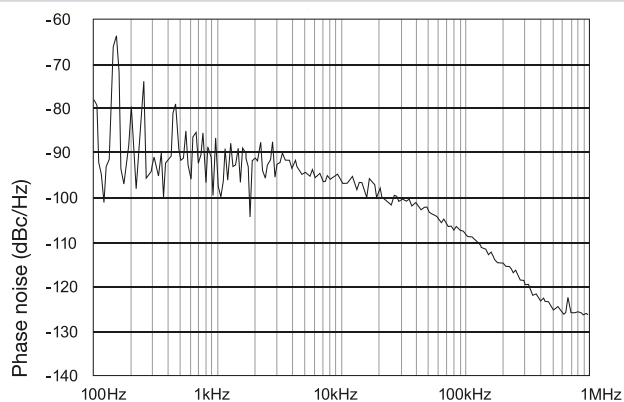
Range	1 Hz...3 GHz
Resolution	1 Hz
Settling time	<10 ms

Frequency Reference 10 MHz

Temperature stability	Standard TCXO; Option OCXO (H085)
0...50°C	$\leq \pm 0,5$ ppm; $\leq \pm 1 \times 10^{-8}$
Aging	$\leq \pm 1$ ppm/year; $\leq \pm 1 \times 10^{-9}$ /day
Internal reference output	
Level	TTL
External reference input	
Level	>0 dBm
Frequency	10 MHz ± 20 ppm

Spectral purity (without modulation)

Harmonics	≤ -30 dBc (typ. < -35 dBc)
Non-harmonics	≤ -50 dBc (> 15 kHz from carrier)
Sub-harmonics $< 2,1$ GHz	≤ -50 dBc
Sub-harmonics $> 2,1$ GHz	≤ -43 dBc (typ. -47 dBc)
Phase noise	(bei 20 kHz from carrier)
$f < 16$ MHz	≤ -120 dBc/Hz
$16 \text{ MHz} \leq f < 250 \text{ MHz}$	≤ -94 dBc/Hz
$250 \text{ MHz} \leq f < 500 \text{ MHz}$	≤ -105 dBc/Hz
$500 \text{ MHz} \leq f < 1.000 \text{ MHz}$	≤ -100 dBc/Hz
$1 \text{ GHz} \leq f < 2 \text{ GHz}$	≤ -95 dBc/Hz
$2 \text{ GHz} \leq f < 3 \text{ GHz}$	≤ -90 dBc/Hz
Residual FM	typ. < 4 Hz; $\leq 6,5$ Hz (in 0.3...3 kHz bandwidth)
Residual AM	typ. $< 0,06\%$ (in 0.03...20 kHz bandwidth)



Output level

Range	-135...+13 dBm
Resolution	0,1 dB
Display-Offset for ext. Attn.	0,0...30,0 dB in 0,1 dB steps
Precision $f < 1,5$ GHz; level > -120 dBm for level > -57 dBm for level < -57 dBm	$\leq \pm 0,7$ dB $\leq \pm (0,7 \text{ dB} + (0,5 \times (-57 \text{ dBm} - \text{level}))/10)$
Precision $f > 1,5$ GHz; level > -120 dBm for level > -57 dBm for level < -57 dBm	$\leq \pm 0,5$ dB $\leq \pm (0,5 \text{ dB} + (0,2 \times (-57 \text{ dBm} - \text{level}))/10)$
Impedance	50 Ω

V.S.W.R.	$f \leq 1 \text{ GHz}$ $f > 1 \text{ GHz}$	$\leq 1,5$; $\leq 2,5$
Modulation sources		
Internal	110 Hz...200 kHz 10 Hz...20 kHz	sine wave, square wave, triangle, sawtooth
Resolution		10 Hz
External		
Impedance		10 k Ω 50 pF
Input level		2 V _{pp} for full scale
Coupling		AC or DC
Output (Front panel)		
Level		2 V _{pp}
Impedance		1 k Ω
Amplitude modulation (Level -30...+7 dBm)		
Source		internal or external
AM depth		0...100%
Resolution		0,1%
Accuracy		$\pm 5\%$ @ $f_{\text{mod}} 1 \text{ kHz}$, $f > 16 \text{ MHz}$
Ext. frequency resp. (to -1 dB)		10 Hz...100 kHz for AC
Distortion		$< 2\%$ (AM-depth $\leq 60\%$, $f_{\text{mod}} \leq 1 \text{ kHz}$) $< 6\%$ (AM-depth $\leq 80\%$, $f_{\text{mod}} < 20 \text{ kHz}$)
Frequency modulation		
Source		internal or external
Deviation		$\pm 200 \text{ Hz}$...400 kHz (depending on frequency band)
Resolution		100 Hz
Accuracy		$\pm 3\%$ + res. FM ($f_{\text{mod}} \leq 5 \text{ kHz}$) $\pm 7\%$ + res. FM ($5 \text{ kHz} < f_{\text{mod}} < 100 \text{ kHz}$)
Ext. frequency response (to -1 dB)		
DC coupling		0...100 kHz
AC coupling		100 Hz...100 kHz
Distortion		$< 1\%$ for deviation $\geq 50 \text{ kHz}$ at 1 kHz $< 3\%$ for deviation $\geq 10 \text{ kHz}$
Phase modulation		
Source		internal or external
Deviation	$< 16 \text{ MHz}$ $> 16 \text{ MHz}$	0...3,14 rad 0...10 rad
Resolution		0,01 rad
Accuracy		$\pm 5\%$ up to 1 kHz + residual PM
Ext. frequency response (to -1 dB)		
DC coupling		0...100 kHz
AC coupling		100 Hz...100 kHz
Distortion		$< 3\%$ for $f_{\text{mod}} = 1 \text{ kHz}$ and deviation = 10 rad
FSK modulation		
Range (F0...F1)		16...3 GHz
Mode		2 FSK levels
Data source		external
Max. rate		10 kbit/s
Shift (F1...F0)		0...10 MHz
Resolution		100 Hz
Accuracy		$\pm 3\%$ + residual FM ($f_{\text{mod}} \leq 5 \text{ kHz}$) $\pm 7\%$ + residual FM ($5 \text{ kHz} < f_{\text{mod}} < 100 \text{ kHz}$)
PSK modulation		
Mode		2 PSK levels
Data source		external
Max. rate		10 kbit/s
Shift (Ph1...Ph0)	$< 16 \text{ MHz}$ $> 16 \text{ MHz}$	0... $\pm 3,14$ rad 0... ± 10 rad

Resolution	0,01 rad
Accuracy	±5% up to 1 kHz + residual PM
Pulse modulation	
Source	external
Dynamic range	f <2 GHz >80 dB f >2 GHz >55 dB
Rise/fall times	<50 ns (typ. <10 ns)
Delay	<100 ns
Max. frequency	2.5 MHz (typ. 5 MHz)
Input level	TTL
Sweep mode	
Range	1...3.200 MHz
Depth	500 Hz...2.999 MHz
Sweep time	20 ms...5 s
Trigger	intern
Protective functions	
The synthesizer is protected against reverse power applied to the RF output up to 1 W for a 50 Ω source and against any DC source up to ±7 V. The protection disconnects the output until manually reset by operator.	
Miscellaneous	
Interface	Dual-Interface USB/RS-232 (HO820), IEEE-488 (GPIB) (optional)
Configuration memories	10
Safety class	Safety Class I (EN61010-1)
Power supply	115/230 V ±10 %, 50...60 Hz, CAT II
Power consumption	ca. 40 VA
Operating temperature	+5...+40 °C
Storage temperature	-20...+70 °C
Rel. humidity	5...80 % (non condensing)
Dimensions (W x H x D)	285 x 75 x 365 mm
Weight	approx. 5 kg

Accessories supplied Line cord, Operating manual, CD

Recommended accessories

HO85 OCXO, temperature stability $\pm 1 \times 10^{-8}$ (Installation only ex factory)

HO880 Interface IEEE-488 (GPIB), galvanically isolated

HZ13 Interface cable (USB) 1.8 m

HZ14 Interface cable (serial) 1 m

HZ20 Adapter, BNC to 4 mm banana

HZ21 Adapter, N male to BNC female

HZ24 Attenuators 50 Ω (3/6/10/20 dB)

HZ33 Test cable 50 Ω, BNC/BNC, 0.5 m

HZ34 Test cable 50 Ω, BNC/BNC, 1.0 m

HZ42 19" Rackmount kit 2RU

HZ72 GPIB-Cable 2 m